

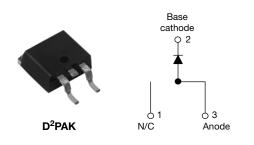
Vishay High Power Products

RoHS

COMPLIANT HALOGEN

FREE

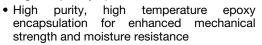
Schottky Rectifier, 8 A



PRODUCT SUMMARY				
I _{F(AV)}	8 A			
V _R	80 V/100 V			

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- High frequency operation



- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 $^\circ \text{C}$
- Halogen-free according to IEC 61249-2-21 definition
- Compliant to RoHS directive 2002/95/EC
- AEC-Q101 qualified

DESCRIPTION

The VS-8TQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	8	А		
V _{RRM}	Range	80/100	V		
I _{FSM}	t _p = 5 μs sine	850	А		
V _F	8 Apk, T _J = 125 °C	0.58	V		
TJ	Range	- 55 to 175	۵°		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-8TQ080GSPbF	VS-8TQ100GSPbF	UNITS	
Maximum DC reverse voltage	V _R	80	100	V	
Maximum working peak reverse voltage	V _{RWM}	80	100	v	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T_C = 157 °C, rectangular waveform 8 A		А	
Maximum peak one cycle non-repetitive surge current		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	850	A
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	230	
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 0.5 \text{ A}, L = 60 \text{ mH}$ 7.50		mJ	
Repetitive avalanche current	I _{AR}			А	

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Schottky Rectifier, 8 A



ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop See fig. 1	V _{FM} ⁽¹⁾	8 A	T _J = 25 °C	0.72	V
		16 A		0.88	
		8 A	- T _J = 125 °C	0.58	
		16 A		0.69	
Maximum reverse leakage current	I _{BM} ⁽¹⁾	$T_J = 25 \ ^\circ C$	V _R = Rated V _R	0.28	mA
See fig. 2	IRM \	T _J = 125 °C		7	ША
Maximum junction capacitance	C _T	V_R = 5 V_{DC} (test signal range 100 kHz to 1 MHz), 25 °C		500	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		8.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R 10 000		V/µs	

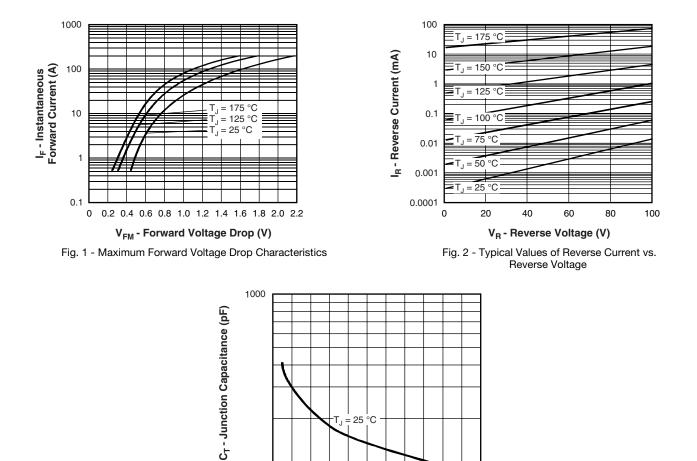
Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature rang	е	T _J , T _{Stg}		- 55 to 175	°C
Maximum thermal resista junction to case	nce,	R _{thJC}	DC operation See fig. 4	2	°C/W
Typical thermal resistance case to heatsink	Э,	R _{thCS}	Mounting surface, smooth and greased	0.50	0/11
Approximate weight				2	g
				0.07	oz.
Mounting torque ——	minimum			6 (5)	kgf · cm
	maximum			12 (10)	(lbf · in)
		$\Omega_{\rm resc} = t_{\rm resc} = \Omega^2 \Omega \Lambda / c_{\rm resc}$	8TQ0	80GS	
Marking device			Case style D ² PAK	8TQ100GS	



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T₁ = 25 °C

10 20 30 40 50 60 70 80 90 100 110 V_R - Reverse Voltage (V) Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

100 0

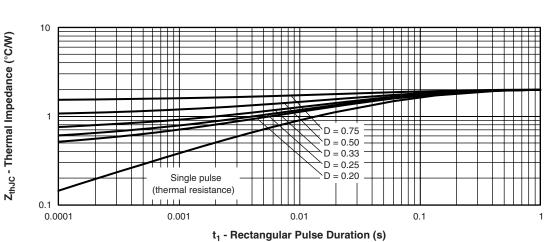
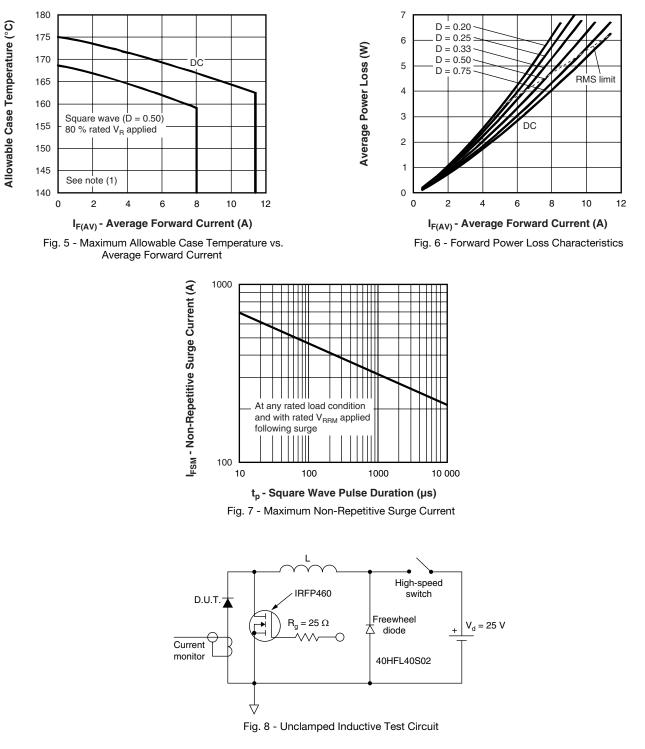


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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Note

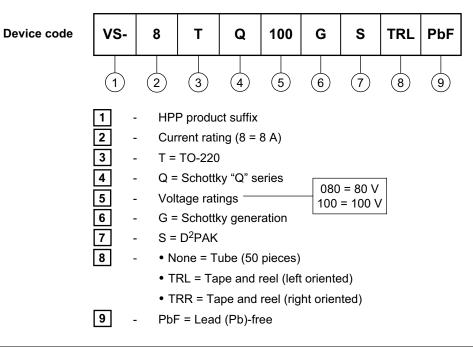
- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC};$
 - $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ \mathsf{x} \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see fig. 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ \mathsf{x} \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$





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ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?95046				
Part marking information	www.vishay.com/doc?95058			
Packaging information	www.vishay.com/doc?95032			
SPICE model	www.vishay.com/doc?95291			



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